NSN 5962-01-141-5694

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View Online at https://aerobasegroup.com/nsn/5962-01-141-5694

Body Length:

Between 0.755 inches and 0.785 inches

Body Width:

Between 0.245 inches and 0.280 inches

Body Height:

0.180 inches

Maximum Power Dissipation Rating:

325.0 milliwatts

Operating Tempurature Range:

+0.0/+70.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Training deb 23259

Features Provided:

Hermetically sealed and asynchronous and programmable and w/enable and w/clock and synchronous

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

8 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 15.0 volts power source

Time Rating Per Chacteristic:

42.00 nanoseconds propagation delay time, low to high level output and 52.00 nanoseconds propagation delay time, high to low level output

output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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